



# STB12NM50N,STD12NM50N,STI12NM50N STF12NM50N, STP12NM50N

N-channel 500 V, 0.29  $\Omega$ , 11 A MDmesh™ II Power MOSFET  
TO-220 - DPAK - D<sup>2</sup>PAK - I<sup>2</sup>PAK - TO-220FP

## Features

Type	V <sub>DSS</sub> (@T <sub>jmax</sub> )	R <sub>DS(on)</sub> max	I <sub>D</sub>
STB12NM50N	550 V	0.38 $\Omega$	11 A
STD12NM50N	550 V	0.38 $\Omega$	11 A
STI12NM50N	550 V	0.38 $\Omega$	11 A
STF12NM50N	550 V	0.38 $\Omega$	11 A <sup>(1)</sup>
STP12NM50N	550 V	0.38 $\Omega$	11 A

- 100% avalanche tested
- Low input capacitance and gate charge
- Low gate input resistance

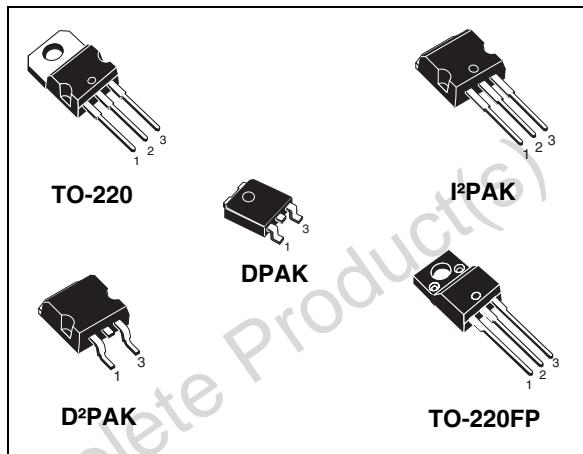


Figure 1. Internal schematic diagram

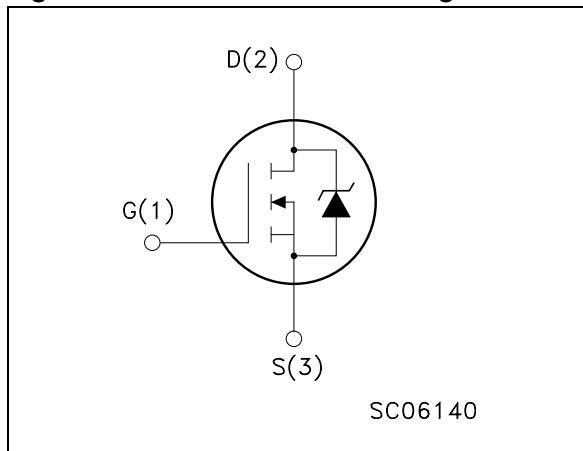


Table 1. Device summary

Order codes	Marking	Package	Packaging
STB12NM50N	B12NM50N	D <sup>2</sup> PAK	Tape and reel
STD12NM50N	D12NM50N	DPAK	Tape and reel
STI12NM50N	I12NM50N	I <sup>2</sup> PAK	Tube
STF12NM50N	F12NM50N	TO-220FP	Tube
STP12NM50N	P12NM50N	TO-220	Tube

## Contents

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# 1 Electrical ratings

**Table 2. Absolute maximum ratings**

Symbol	Parameter	Value		Unit
		TO-220 / I <sup>2</sup> PAK D <sup>2</sup> PAK / DPAK	TO-220FP	
V <sub>DS</sub>	Drain-source voltage ( $V_{GS} = 0$ )	500		V
V <sub>GS</sub>	Gate-source voltage	$\pm 25$		V
I <sub>D</sub>	Drain current (continuous) at $T_C = 25^\circ\text{C}$	11	11 <sup>(1)</sup>	A
I <sub>D</sub>	Drain current (continuous) at $T_C=100^\circ\text{C}$	6.7	6.7 <sup>(1)</sup>	A
I <sub>DM</sub> <sup>(2)</sup>	Drain current (pulsed)	44	44 <sup>(1)</sup>	A
P <sub>TOT</sub>	Total dissipation at $T_C = 25^\circ\text{C}$	100	25	W
dv/dt <sup>(3)</sup>	Peak diode recovery voltage slope	15		V/ns
V <sub>ISO</sub>	Insulation withstand voltage (RMS) from all three leads to external heat sink ( $t=1\text{ s}; T_C=25^\circ\text{C}$ )	--	2500	V
T <sub>stg</sub>	Storage temperature	-55 to 150		°C
T <sub>J</sub>	Max. operating junction temperature	150		°C

1. Limited only by maximum temperature allowed
2. Pulse width limited by safe operating area
3.  $I_{SD} \leq 11\text{A}$ ,  $dI/dt \leq 400\text{A}/\mu\text{s}$ ,  $V_{DD} = 80\%V_{(BR)DSS}$

**Table 3. Thermal data**

Symbol	Parameter	Value					Unit
		TO-220	I <sup>2</sup> PAK	DPAK	D <sup>2</sup> PAK	TO-220FP	
R <sub>thj-case</sub>	Thermal resistance junction-case max	1.25			5		°C/W
R <sub>thj-amb</sub>	Thermal resistance junction-amb max	62.5	--	--	62.5		°C/W
R <sub>thj-pcb</sub>	Thermal resistance junction-pcb max	--	--	50	30	--	°C/W
T <sub>I</sub>	Maximum lead temperature for soldering purposes	300					°C

**Table 4. Avalanche characteristics**

Symbol	Parameter	Value	Unit
I <sub>AS</sub>	Avalanche current, repetitive or not-repetitive (pulse width limited by T <sub>j</sub> Max)	5	A
E <sub>AS</sub>	Single pulse avalanche energy (starting T <sub>j</sub> =25°C, I <sub>d</sub> =I <sub>AS</sub> , V <sub>dd</sub> =50V)	350	mJ

## 2 Electrical characteristics

( $T_{CASE}=25\text{ }^{\circ}\text{C}$  unless otherwise specified)

**Table 5. On/off states**

Symbol	Parameter	Test conditions	Min	Typ.	Max	Unit
$V_{(BR)DSS}$	Drain-source breakdown voltage	$I_D = 1\text{ mA}, V_{GS} = 0$	500			V
$dv/dt^{(1)}$	Peak diode recovery voltage slope	$V_{DD}=400\text{ V}, I_D=11\text{ A}, V_{GS}=10\text{ V}$		44		V/ns
$I_{DSS}$	Zero gate voltage drain current ( $V_{GS} = 0$ )	$V_{DS} = \text{max rating}, V_{DS} = \text{max rating}@125\text{ }^{\circ}\text{C}$			1 100	$\mu\text{A}$ $\mu\text{A}$
$I_{GSS}$	Gate body leakage current ( $V_{DS} = 0$ )	$V_{GS} = \pm 20\text{ V}$			100	nA
$V_{GS(\text{th})}$	Gate threshold voltage	$V_{DS} = V_{GS}, I_D = 250\text{ }\mu\text{A}$	2	3	4	V
$R_{DS(\text{on})}$	Static drain-source on resistance	$V_{GS} = 10\text{ V}, I_D = 5.5\text{ A}$		0.29	0.38	$\Omega$

1. Characteristic value at turn off inductive load

**Table 6. Dynamic**

Symbol	Parameter	Test conditions	Min	Typ.	Max	Unit
$g_{fs}^{(1)}$	Forward transconductance	$V_{DS} = 15\text{ V}, I_D = 5.5\text{ A}$		8		S
$C_{iss}$ $C_{oss}$ $C_{rss}$	Input capacitance Output capacitance Reverse transfer capacitance	$V_{DS} = 50\text{ V}, f=1\text{ MHz}, V_{GS}=0$		940 100 10		pF pF pF
$C_{oss\text{ eq}}^{(2)}$	Equivalent output capacitance	$V_{GS}=0, V_{DS} = 0 \text{ to } 400\text{ V}$		130		pF
$Q_g$ $Q_{gs}$ $Q_{gd}$	Total gate charge Gate-source charge Gate-drain charge	$V_{DD}=400\text{ V}, I_D = 11\text{ A}$ $V_{GS} = 10\text{ V}$ <i>(see Figure 17)</i>		30 6 15		nC nC nC
$R_g$	Gate input resistance	f=1 MHz Gate DC Bias=0 test signal level=20 mV open drain		4.5		$\Omega$

1. Pulsed: pulse duration=300  $\mu\text{s}$ , duty cycle 1.5%

2.  $C_{oss\text{ eq}}$  is defined as a constant equivalent capacitance giving the same charging time as  $C_{oss}$  when  $V_{DS}$  increases from 0 to 80%  $V_{DSS}$

**Table 7. Switching times**

Symbol	Parameter	Test conditions	Min	Typ.	Max	Unit
$t_{d(on)}$	Turn-on delay time	$V_{DD}=250\text{ V}$ , $I_D=5.5\text{ A}$ , $R_G=4.7\text{ }\Omega$ , $V_{GS}=10\text{ V}$ (see Figure 16)	15 15 60 14	ns ns ns ns	ns ns ns ns	ns ns ns ns
$t_r$	Rise time					
$t_{d(off)}$	Turn-off delay time					
$t_f$	Fall time					

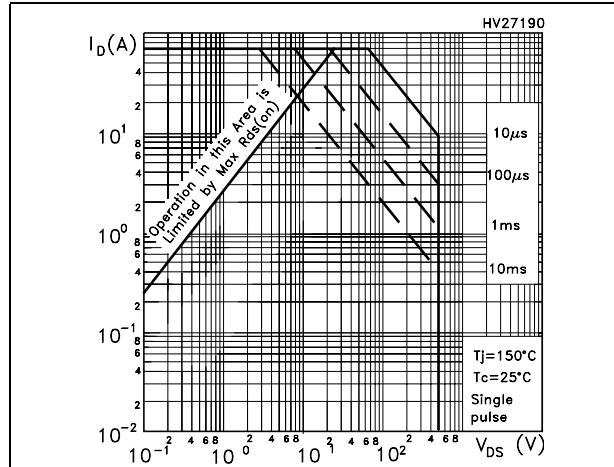
**Table 8. Source drain diode**

Symbol	Parameter	Test conditions	Min	Typ.	Max	Unit
$I_{SD}$	Source-drain current				11	A
$I_{SDM}^{(1)}$	Source-drain current (pulsed)				44	A
$V_{SD}^{(2)}$	Forward on voltage	$I_{SD}=11\text{ A}$ , $V_{GS}=0$			1.3	V
$t_{rr}$ $Q_{rr}$ $I_{RRM}$	Reverse recovery time Reverse recovery charge Reverse recovery current	$I_{SD}=11\text{ A}$ , $V_{DD}=100\text{ V}$ $di/dt = 100\text{ A}/\mu\text{s}$ , (see Figure 18)		340 3.5 20		ns $\mu\text{C}$ A
$t_{rr}$ $Q_{rr}$ $I_{RRM}$	Reverse recovery time Reverse recovery charge Reverse recovery current	$I_{SD}=11\text{ A}$ , $di/dt = 100\text{ A}/\mu\text{s}$ , $V_{DD}=100\text{ V}$ , $T_j=150\text{ }^\circ\text{C}$ (see Figure 18)		420 4 20		ns $\mu\text{C}$ A

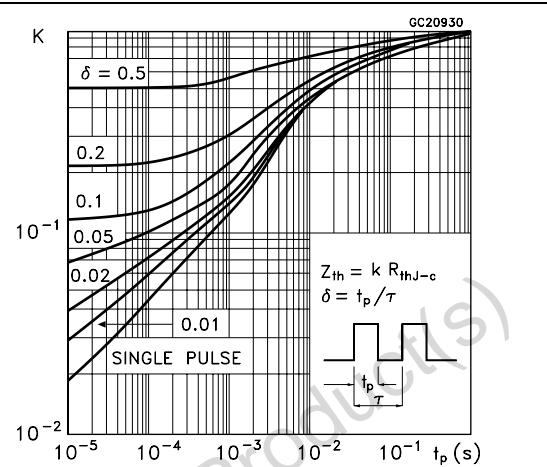
1. Pulse width limited by safe operating area
2. Pulsed: pulse duration=300  $\mu\text{s}$ , duty cycle 1.5%

## 2.1 Electrical characteristics (curves)

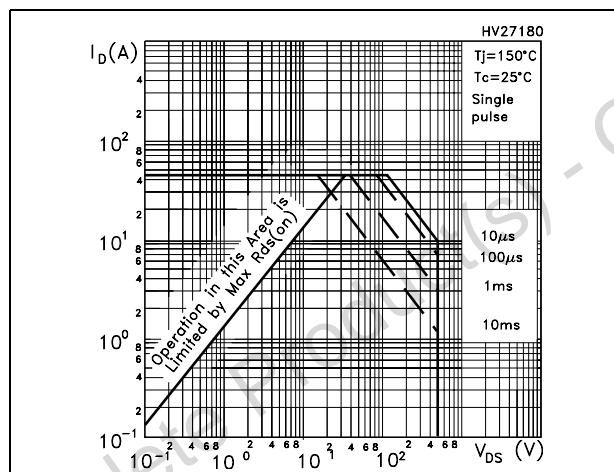
**Figure 2.** Safe operating area for TO-220/DPAK/ D<sup>2</sup>PAK / I<sup>2</sup>PAK



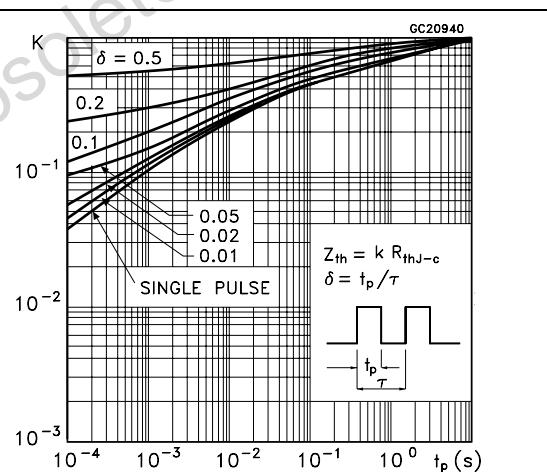
**Figure 3.** Thermal impedance for TO-220/DPAK/ D<sup>2</sup>PAK / I<sup>2</sup>PAK



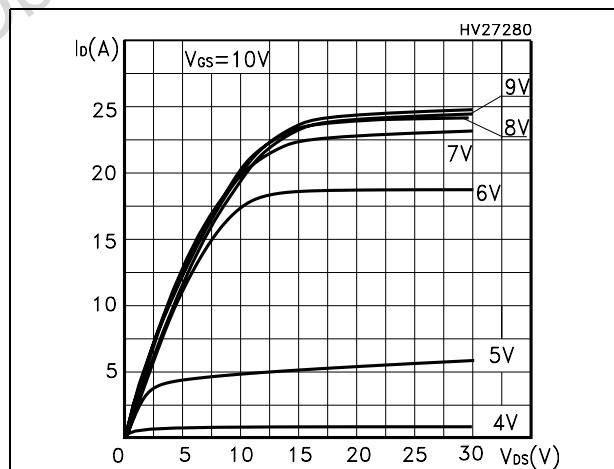
**Figure 4.** Safe operating area for TO-220FP



**Figure 5.** Thermal impedance for TO-220FP



**Figure 6.** Output characteristics



**Figure 7.** Transfer characteristics

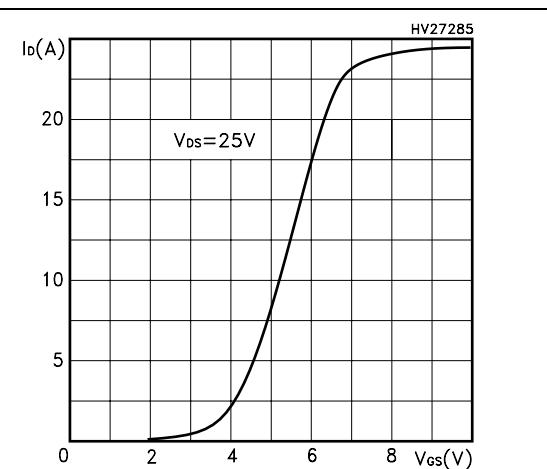


Figure 8. Transconductance

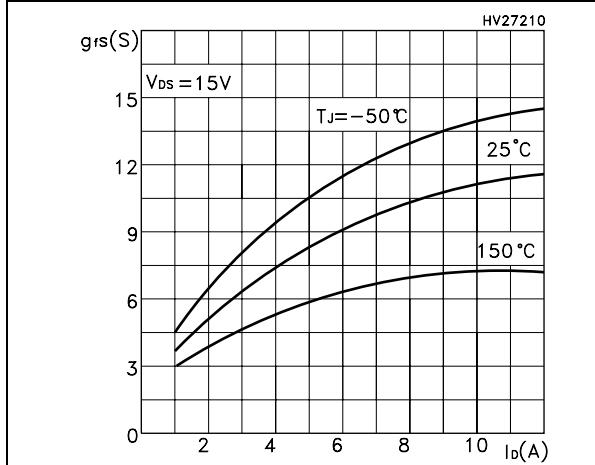


Figure 9. Static drain-source on resistance

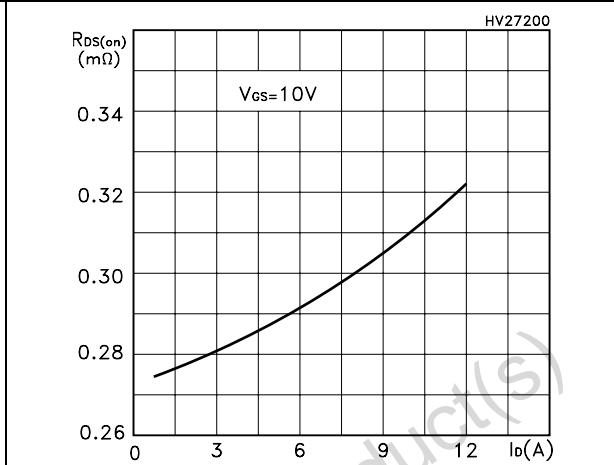


Figure 10. Gate charge vs gate-source voltage

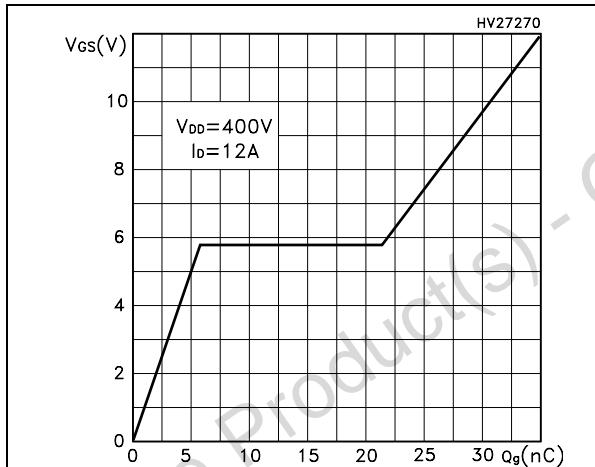


Figure 11. Capacitance variations

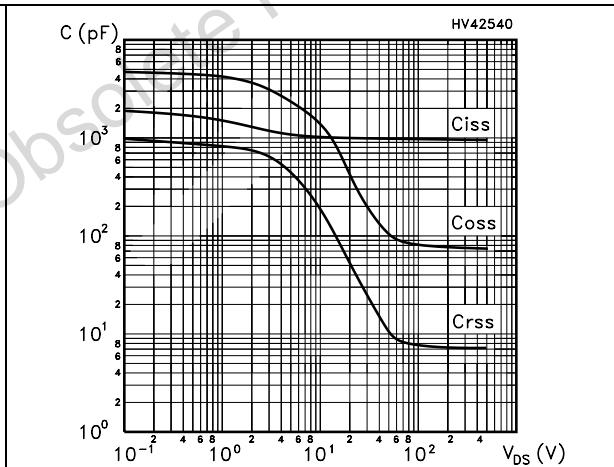
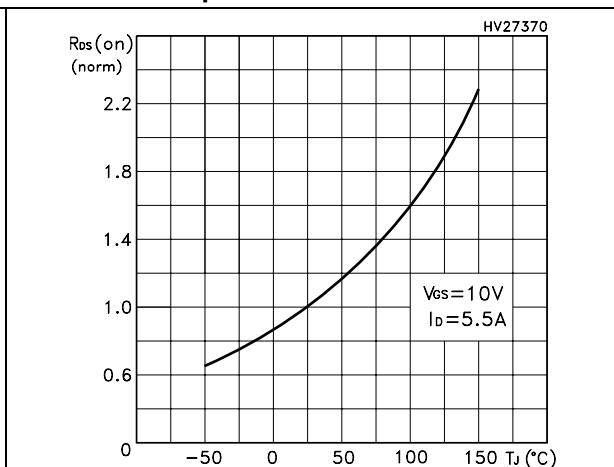
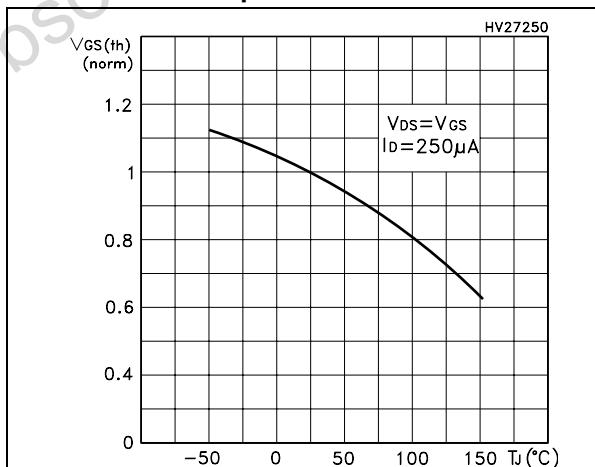
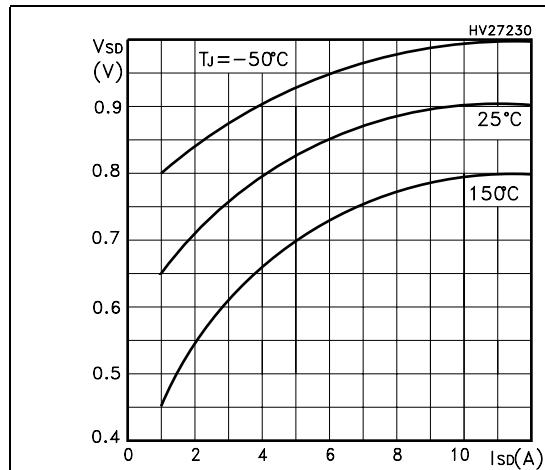
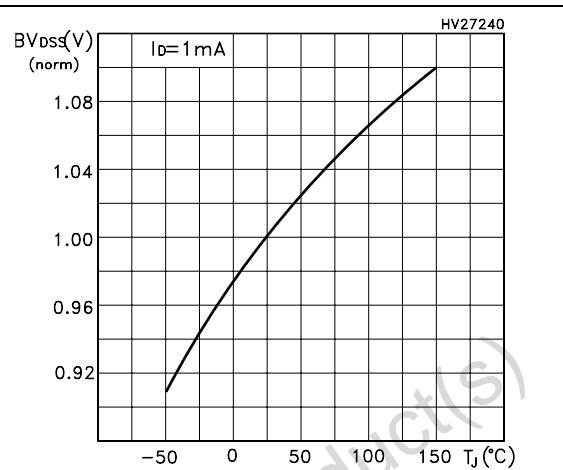


Figure 12. Normalized gate threshold voltage vs temperature

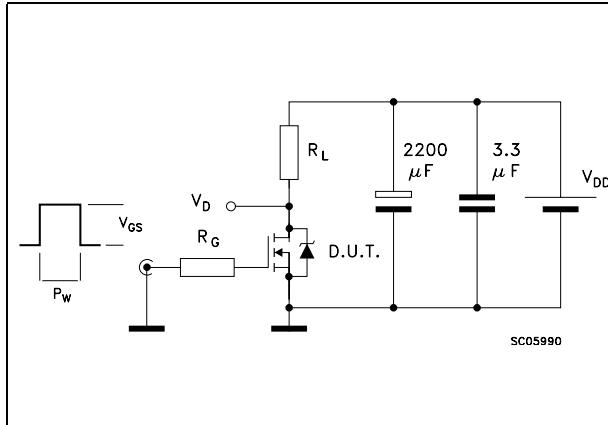
Figure 13. Normalized on resistance vs temperature



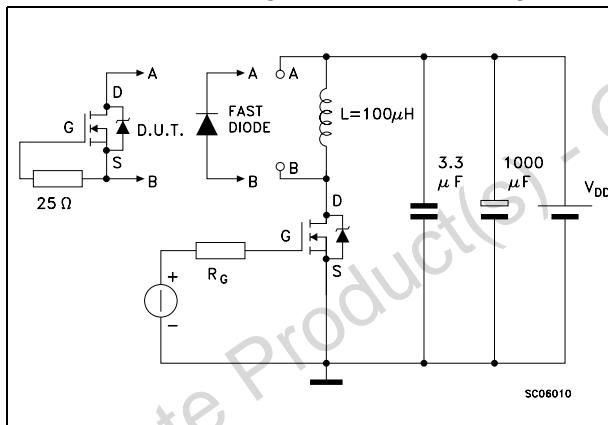
**Figure 14. Source-drain diode forward characteristics****Figure 15. Normalized  $B_{VDSS}$  vs temperature**

### 3 Test circuit

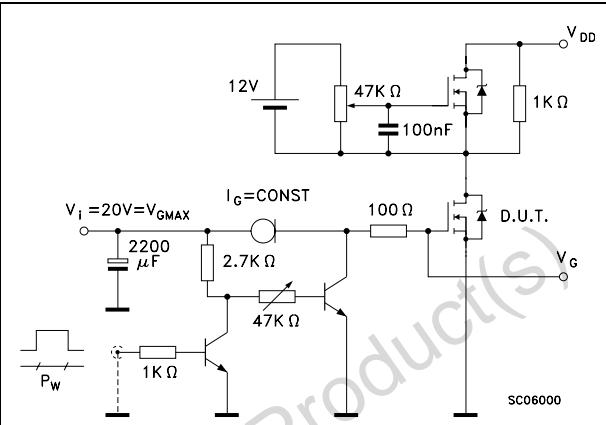
**Figure 16. Switching times test circuit for resistive load**



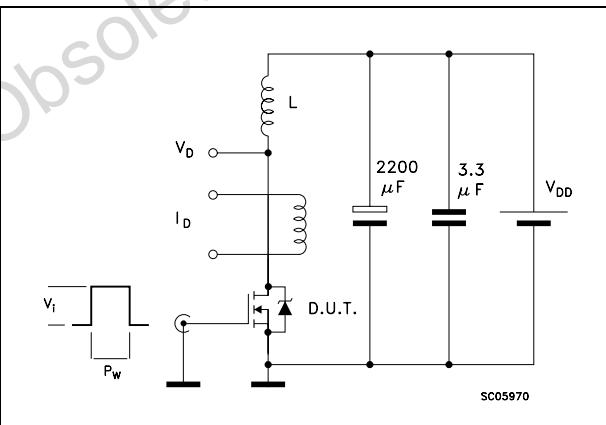
**Figure 18. Test circuit for inductive load switching and diode recovery times**



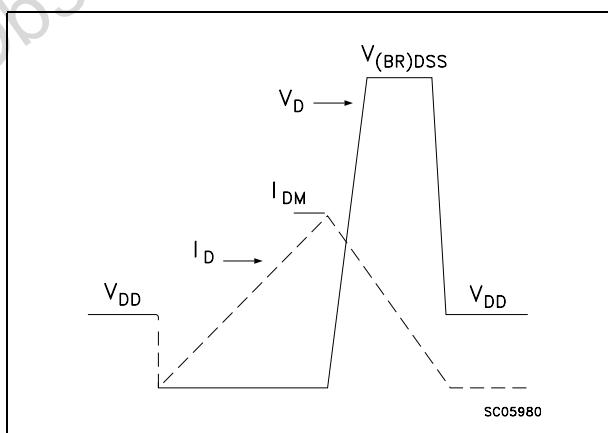
**Figure 17. Gate charge test circuit**



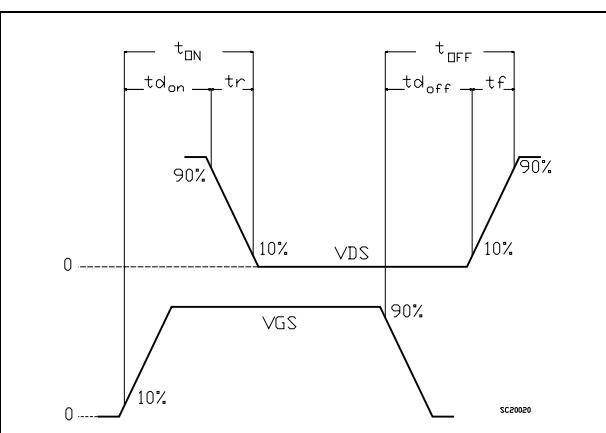
**Figure 19. Unclamped Inductive load test circuit**



**Figure 20. Unclamped inductive waveform**



**Figure 21. Switching time waveform**

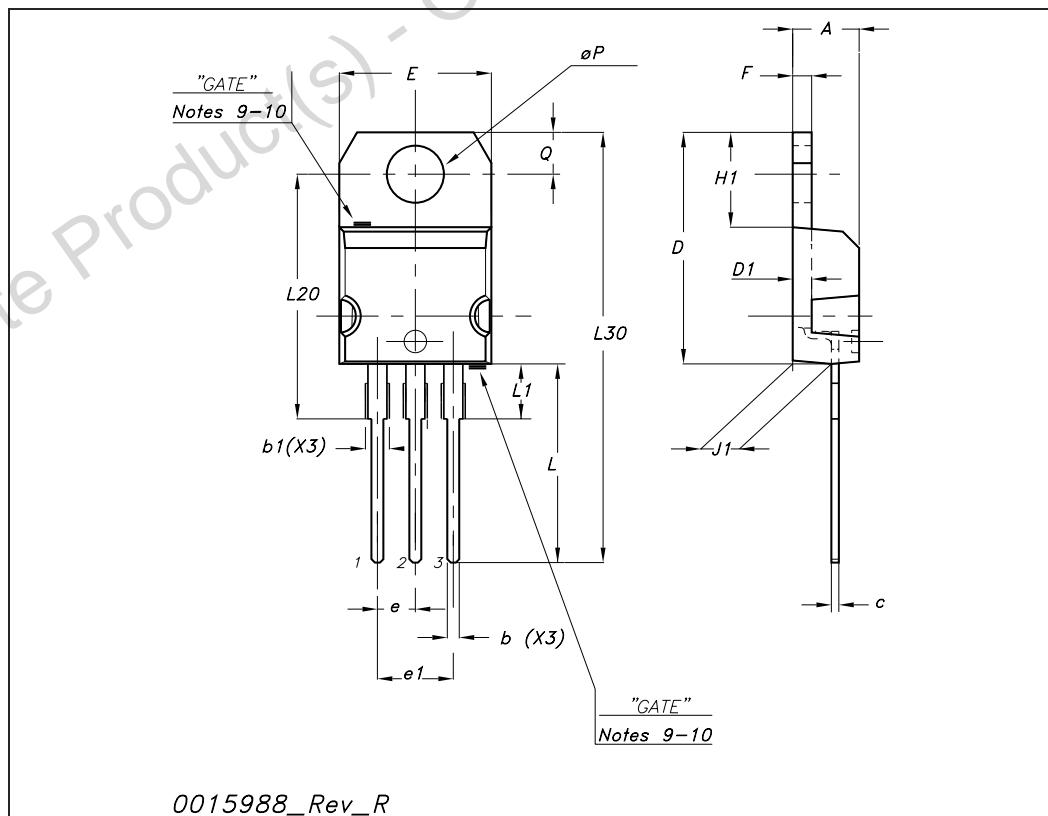


## 4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: [www.st.com](http://www.st.com)

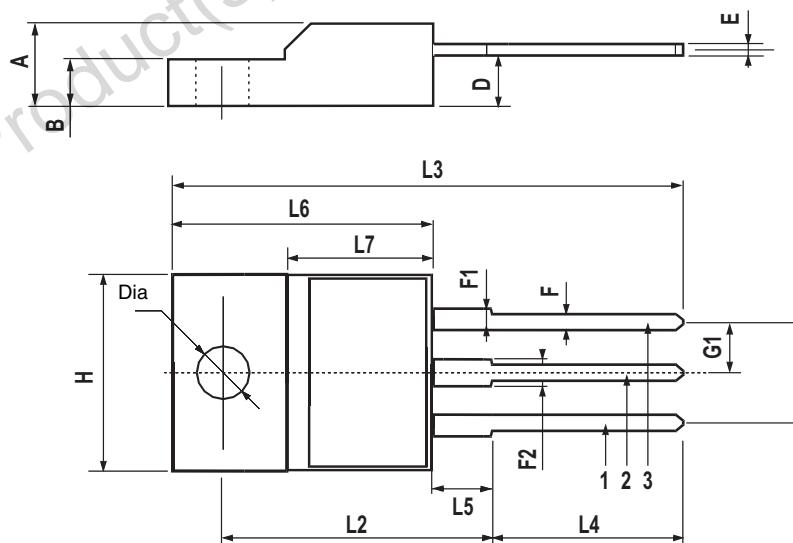
## TO-220 mechanical data

Dim	mm			inch		
	Min	Typ	Max	Min	Typ	Max
A	4.40		4.60	0.173		0.181
b	0.61		0.88	0.024		0.034
b1	1.14		1.70	0.044		0.066
c	0.48		0.70	0.019		0.027
D	15.25		15.75	0.6		0.62
D1		1.27			0.050	
E	10		10.40	0.393		0.409
e	2.40		2.70	0.094		0.106
e1	4.95		5.15	0.194		0.202
F	1.23		1.32	0.048		0.051
H1	6.20		6.60	0.244		0.256
J1	2.40		2.72	0.094		0.107
L	13		14	0.511		0.551
L1	3.50		3.93	0.137		0.154
L20		16.40			0.645	
L30		28.90			1.137	
$\emptyset P$	3.75		3.85	0.147		0.151
Q	2.65		2.95	0.104		0.116



## TO-220FP mechanical data

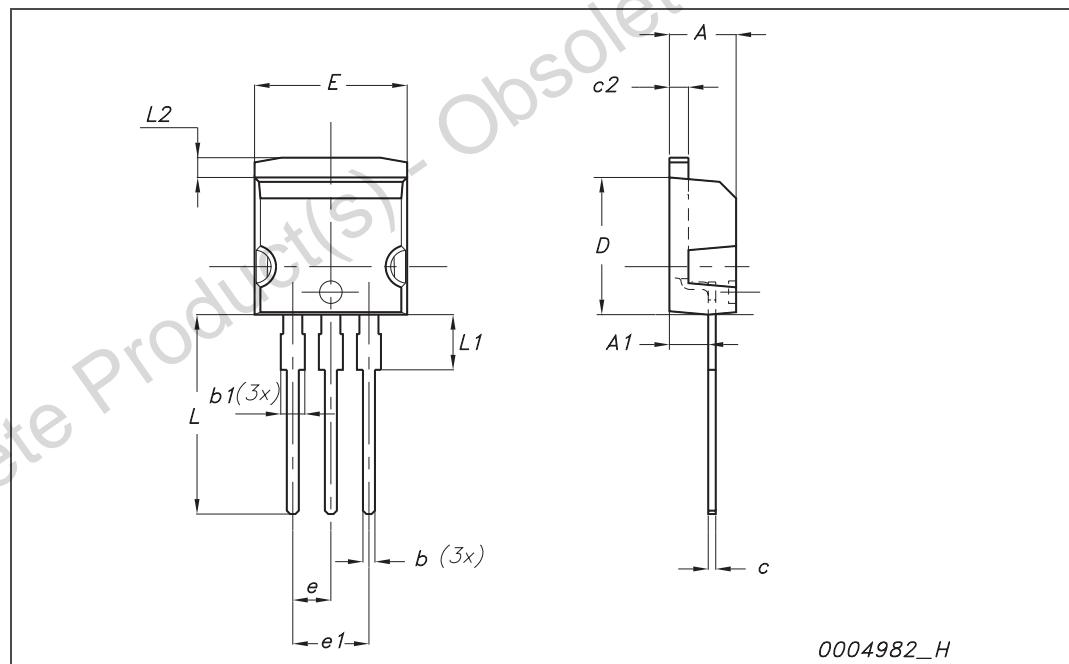
Dim.	mm.			inch		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	2.5		2.7	0.098		0.106
D	2.5		2.75	0.098		0.108
E	0.45		0.70	0.017		0.027
F	0.75		1.00	0.030		0.039
F1	1.15		1.50	0.045		0.067
F2	1.15		1.50	0.045		0.067
G	4.95		5.20	0.195		0.204
G1	2.40		2.70	0.094		0.106
H	10		10.40	0.393		0.409
L2		16			0.630	
L3	28.6		30.6	1.126		1.204
L4	9.80		10.60	0.385		0.417
L5	2.9		3.6	0.114		0.141
L6	15.90		16.40	0.626		0.645
L7	9		9.30	0.354		0.366
Dia	3		3.2	0.118		0.126



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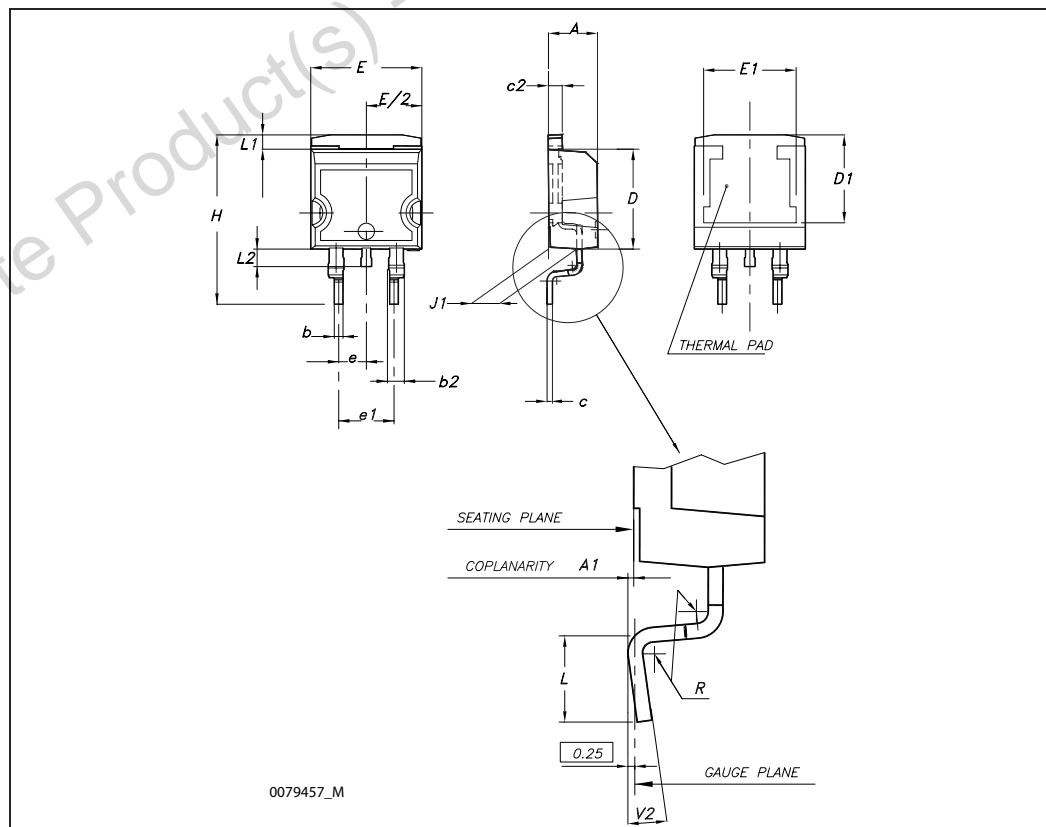
I<sup>2</sup>PAK (TO-262) mechanical data

Dim	mm			inch		
	Min	Typ	Max	Min	Typ	Max
A	4.40		4.60	0.173		0.181
A1	2.40		2.72	0.094		0.107
b	0.61		0.88	0.024		0.034
b1	1.14		1.70	0.044		0.066
c	0.49		0.70	0.019		0.027
c2	1.23		1.32	0.048		0.052
D	8.95		9.35	0.352		0.368
e	2.40		2.70	0.094		0.106
e1	4.95		5.15	0.194		0.202
E	10		10.40	0.393		0.410
L	13		14	0.511		0.551
L1	3.50		3.93	0.137		0.154
L2	1.27		1.40	0.050		0.055



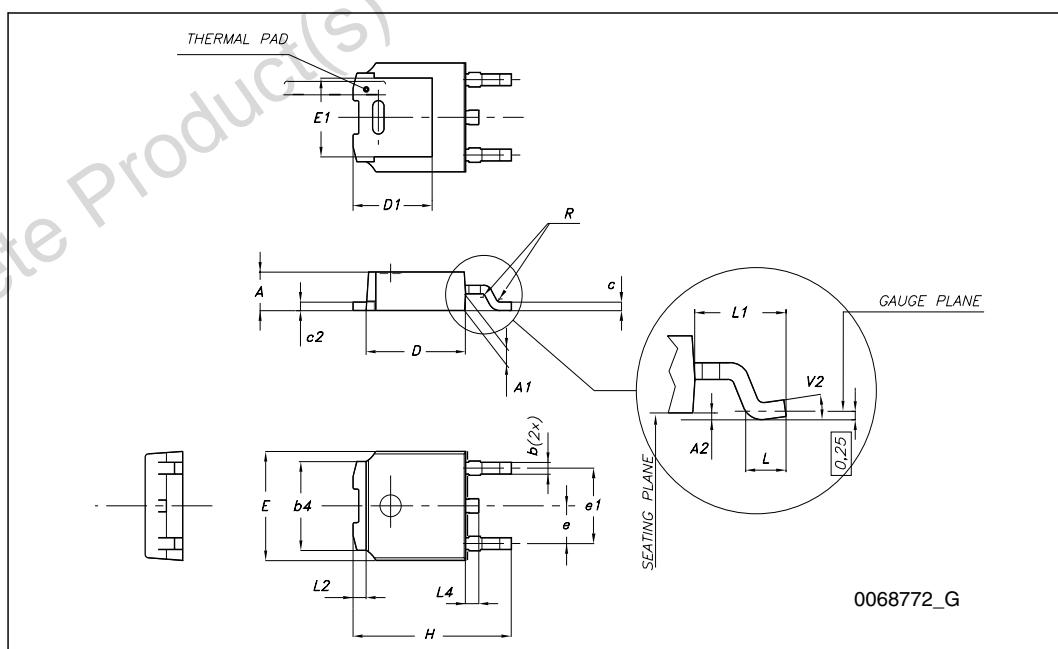
D<sup>2</sup>PAK (TO-263) mechanical data

Dim	mm			inch		
	Min	Typ	Max	Min	Typ	Max
A	4.40		4.60	0.173		0.181
A1	0.03		0.23	0.001		0.009
b	0.70		0.93	0.027		0.037
b2	1.14		1.70	0.045		0.067
c	0.45		0.60	0.017		0.024
c2	1.23		1.36	0.048		0.053
D	8.95		9.35	0.352		0.368
D1	7.50			0.295		
E	10		10.40	0.394		0.409
E1	8.50			0.334		
e		2.54			0.1	
e1	4.88		5.28	0.192		0.208
H	15		15.85	0.590		0.624
J1	2.49		2.69	0.099		0.106
L	2.29		2.79	0.090		0.110
L1	1.27		1.40	0.05		0.055
L2	1.30		1.75	0.051		0.069
R		0.4			0.016	
V2	0°		8°	0°		8°



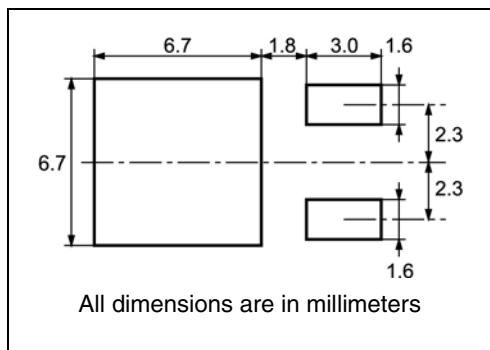
## TO-252 (DPAK) mechanical data

DIM.	mm.		
	min.	typ	max.
A	2.20		2.40
A1	0.90		1.10
A2	0.03		0.23
b	0.64		0.90
b4	5.20		5.40
c	0.45		0.60
c2	0.48		0.60
D	6.00		6.20
D1		5.10	
E	6.40		6.60
E1		4.70	
e		2.28	
e1	4.40		4.60
H	9.35		10.10
L	1		
L1		2.80	
L2		0.80	
L4	0.60		1
R		0.20	
V2	0 °		8 °

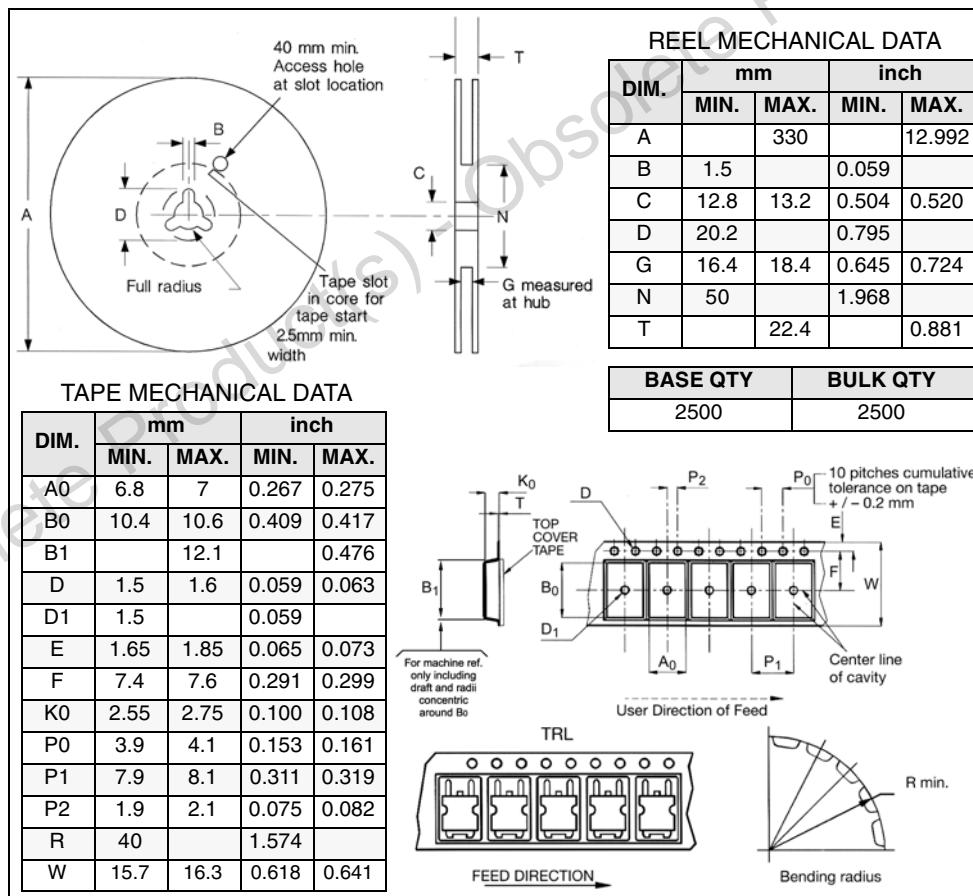


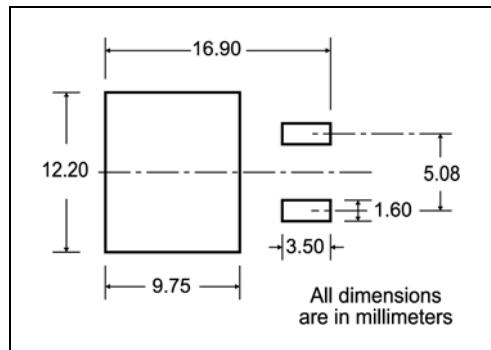
## 5 Packaging mechanical data

DPAK FOOTPRINT



## TAPE AND REEL SHIPMENT



**D<sup>2</sup>PAK FOOTPRINT****TAPE AND REEL SHIPMENT**

REEL MECHANICAL DATA				
DIM.	mm		inch	
	MIN.	MAX.	MIN.	MAX.
A			330	
B	1.5		0.059	
C	12.8	13.2	0.504	0.520
D	20.2		0.795	
G	24.4	26.4	0.960	1.039
N	100		3.937	
T			30.4	1.197
BASE QTY		BULK QTY		
1000		1000		

DIM.	mm		inch	
	MIN.	MAX.	MIN.	MAX.
A0	10.5	10.7	0.413	0.421
B0	15.7	15.9	0.618	0.626
D	1.5	1.6	0.059	0.063
D1	1.59	1.61	0.062	0.063
E	1.65	1.85	0.065	0.073
F	11.4	11.6	0.449	0.456
K0	4.8	5.0	0.189	0.197
P0	3.9	4.1	0.153	0.161
P1	11.9	12.1	0.468	0.476
P2	1.9	2.1	0.075	0.082
R	50		1.574	
T	0.25	0.35	0.0098	0.0137
W	23.7	24.3	0.933	0.956

\* on sales type

## 6 Revision history

**Table 9. Document revision history**

Date	Revision	Changes
24-May-2005	1	Initial release
10-Jun-2005	2	Inserted new row in <i>Table 7.: Switching times</i>
28-Sep-2005	3	Document status promoted from preliminary data to datasheet.
14-Oct-2005	4	Modified <i>Figure 6, Figure 9</i>
06-Mar-2006	5	Modified <i>Figure 8</i>
29-Mar-2006	6	Modified value on <i>Table 5.</i>
14-Nov-2006	7	Document reformatted no content change
24-Jul-2008	8	<ul style="list-style-type: none"><li>– Added I<sup>2</sup>PAK;</li><li>– <i>Table 3: Thermal data</i> has been updated;</li><li>– <i>Figure 11: Capacitance variations</i> changed.</li></ul>

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